

Laser System for Spectroscopy of $^{209}\text{Bi}^{82+}$ @ 243.9 nm

Status Report

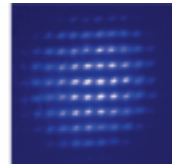


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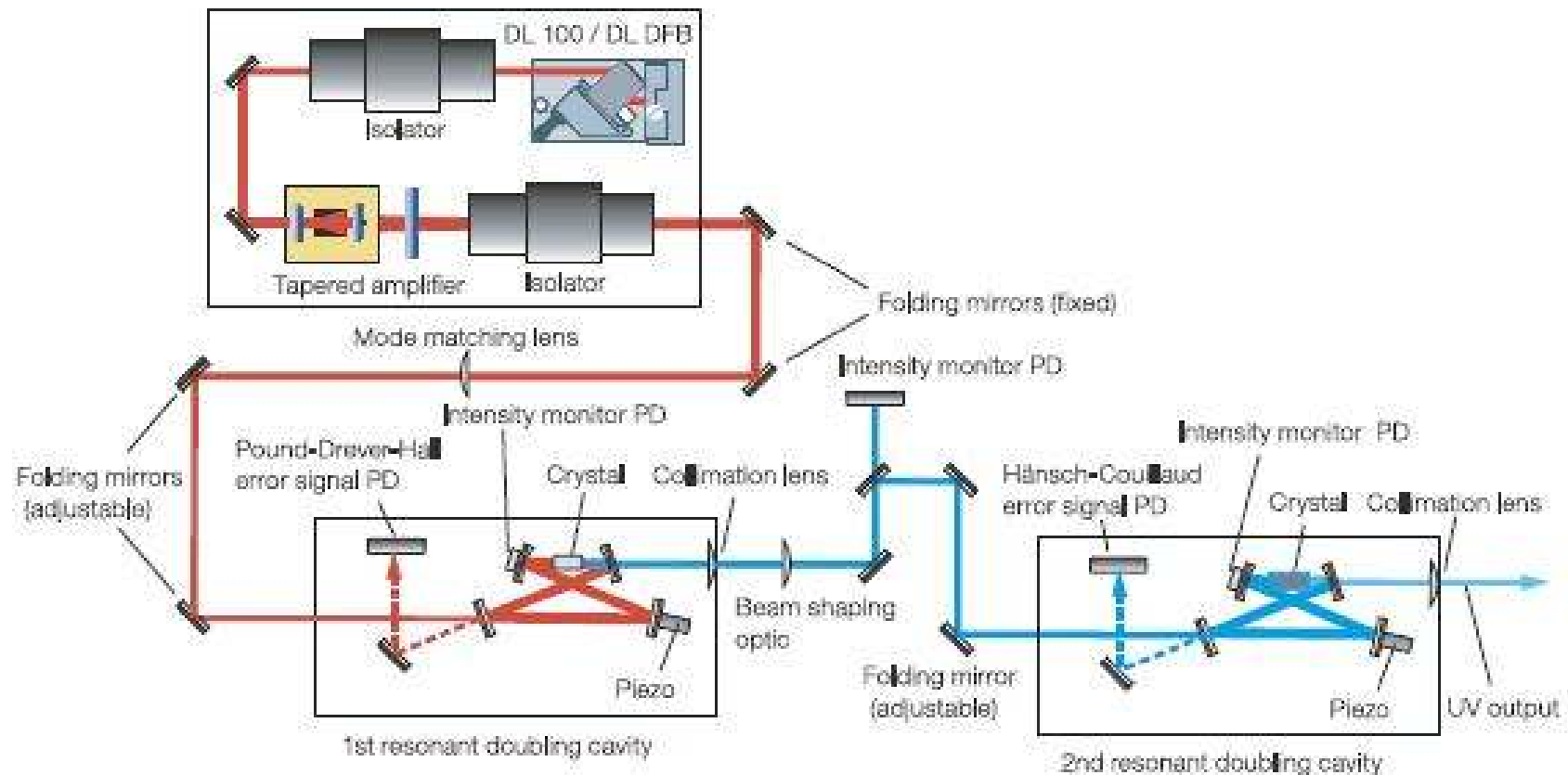
SPECTRAP Meeting 2nd of July 2008

Overview



- commercial UV laser system @ 243.9 nm based on a frequency quadrupled MOPA @ 976 nm
- frequency stabilization scheme:
 - DL @ 780 nm locked on Rb-D2 line
 - transfer cavity locked on DL @ 780 nm
 - MOPA system locked on the transfer cavity
- outlook: test of the laser system under experimental conditions

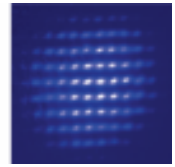
Reminder: Toptica laser system TA-FHG-110



Setup for fourth harmonic generation, involving two cascaded doubling stages.

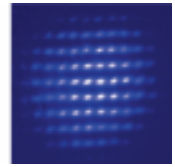
Toptica laser system TA-FHG-110: Specifications

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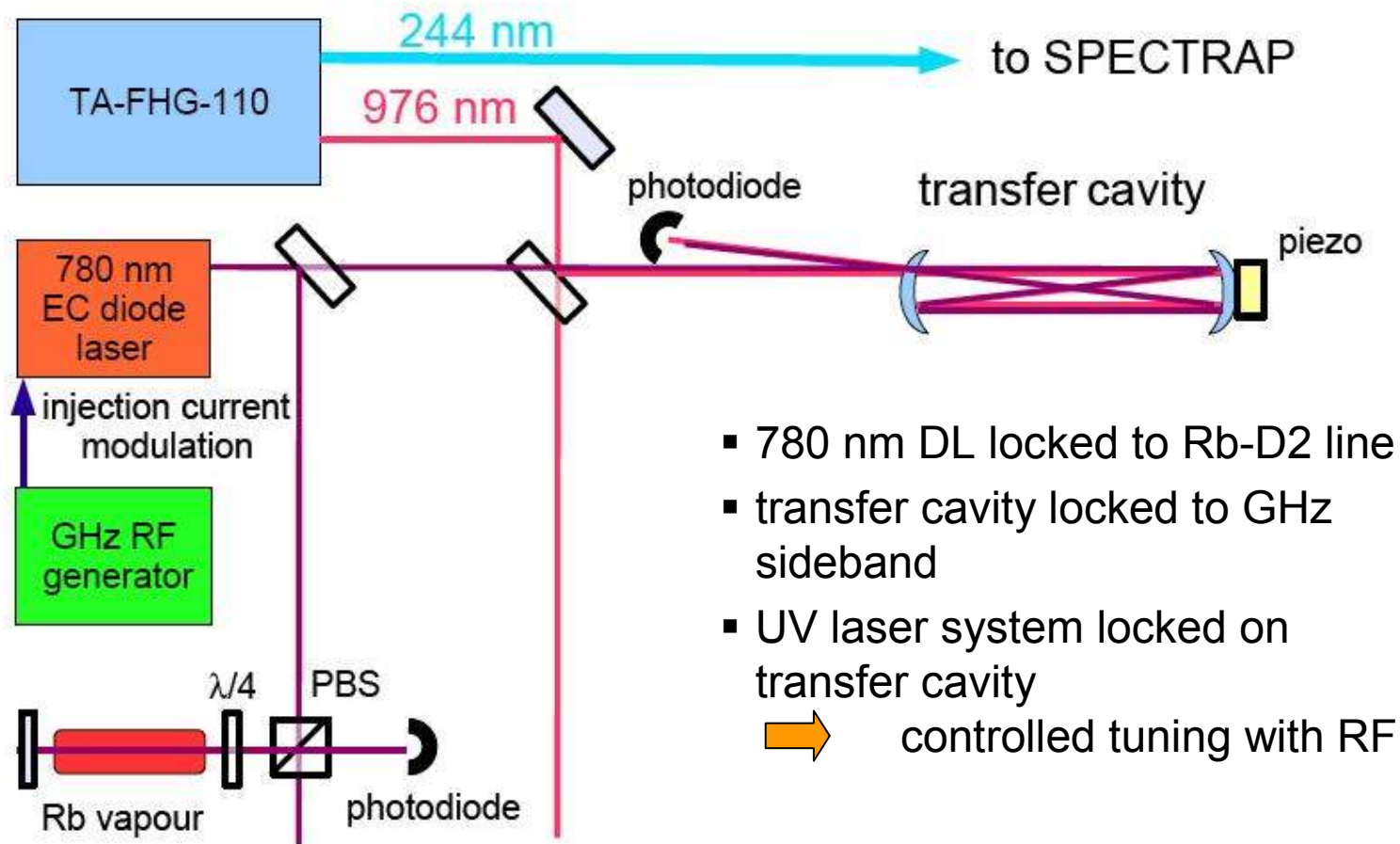
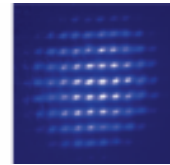
- output power of MOPA system: 1000 mW @ 976 nm
- output power UV: 15 mW @ 241 – 246 nm (confirmed during installation)
29 mW @ 243,9 nm (measured during installation)
- Mode-hop free scan range in UV: 25 GHz (during installation: 40 GHz)
- linewidth of UV-light: < 4 MHz over 5 μ s

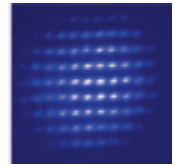
Toptica laser system TA-FHG-110: Some remarks on the specifications



- the demanded specifications are fully met
- no verification of the linewidth yet
 - ➔ characterization when IR FPI is ready
- acoustic noise affects Hänsch-Couillaud-lock of 2nd doubling cavity
 - ➔ acoustic isolation box around UV laser system recommended

Frequency stabilization to transfer cavity: Scheme I





Remarks on stabilization scheme I

design, implementation and testing of RF side band generation:

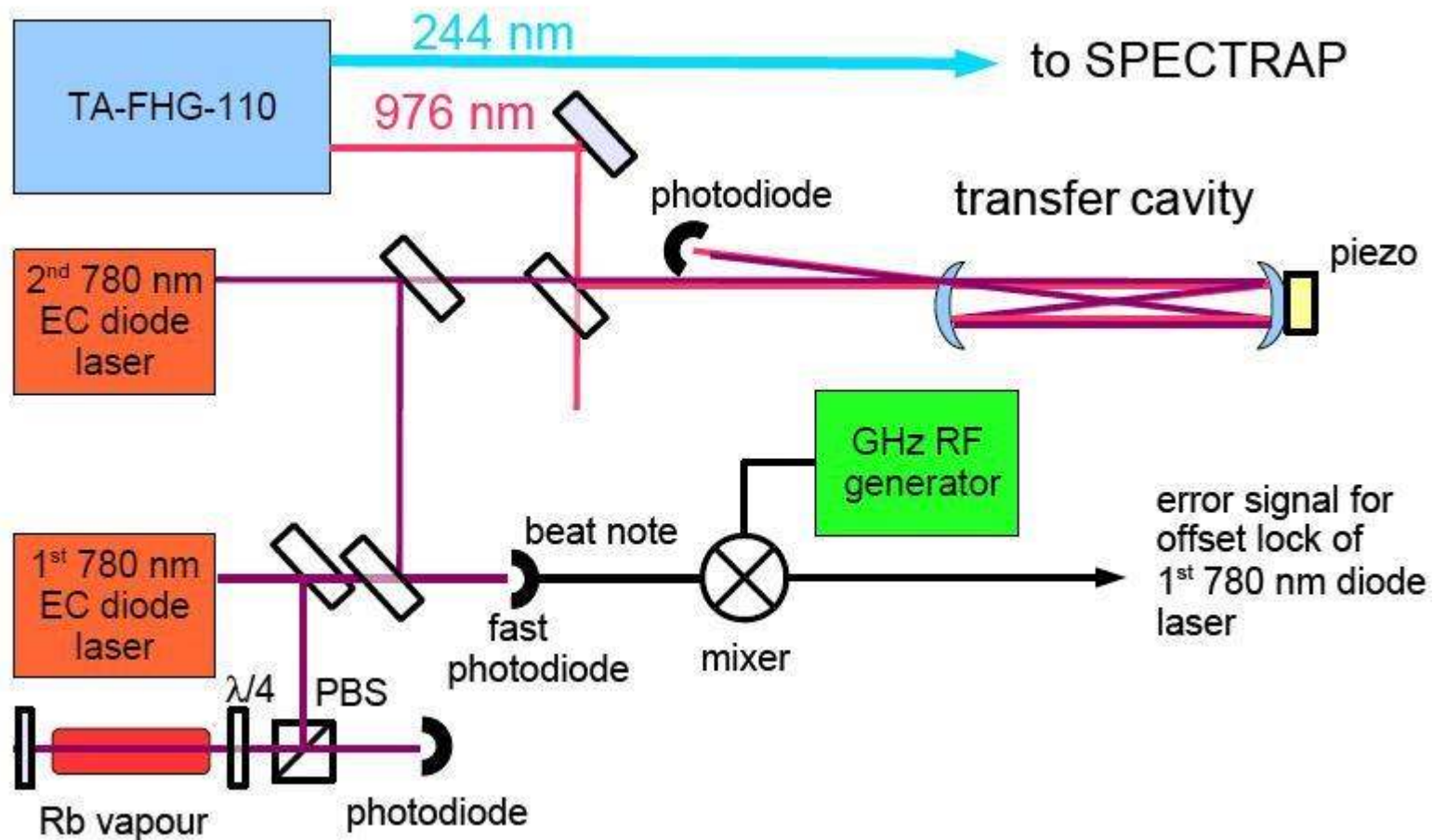
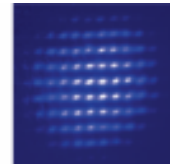
- works in principle
- usable side band signal from 2 to 8 GHz with smooth amplitude change
- detection with lock-in amplifier
 - ➔ better signal to noise ratio
 - ➔ error signal for locking

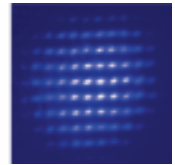
drawbacks:

- short transfer cavity necessary (FSR about 10 GHz)
- finesse cannot be low ➔ no efficient detection of side band signal

➔ switch to 2nd scheme to lock transfer cavity with adjustable offset frequency

Frequency stabilization to transfer cavity: Scheme II

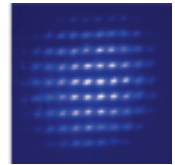




Details of scheme II

- 1st 780 nm DL locked on Rb-D2 line
- 2nd 780 nm DL locked on 1st with offset lock
 - ➔ beat note on a fast photodiode is measured
 - ➔ beat signal is mixed with a GHz RF signal
 - ➔ difference frequency is divided by 64
 - ➔ divided signal is converted to a DC voltage by frequency to voltage converter
 - ➔ linear ramp with flexible lock point is generated
- transfer cavity is locked on 2nd DL with side-of-fringe lock
- UV laser system is locked on transfer cavity with side-of-fringe lock
 - ➔ UV frequency tunable with change of the mixing GHz radio frequency

Remarks on stabilization scheme II



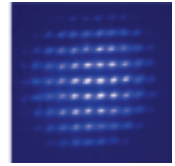
presently:

- installation of 2nd external cavity DL @ 780 nm
- frequency offset lock electronics is ordered or built respectively
- mechanical design of the transfer cavity has been finished and its construction is nearly completed
- cavity mirror substrates have been ordered and delivered 2 weeks ago
 - ➡ inhouse Ag coating has been tested
- side-of-fringe lock electronics is ready

➡ hopefully most of the work will be done within the next four weeks!

Outlook: Test of the laser system under experimental conditions

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necessary:

- characterization of frequency stabilization of the whole laser system
- check of frequency stabilization

possible test: spectroscopy with hollow cathode lamps

- ➔ search for atomic transitions near 243.9 nm
- ➔ possible test candidate: Pt @ 244 nm